

TP0310K

27dBm CW 0.1-3.8GHz GaAs Power LNA

Application Note: TP0310K EVB A

Application Note 1700MHz~2000MHz 5.0V 140mA

Rev-1.1



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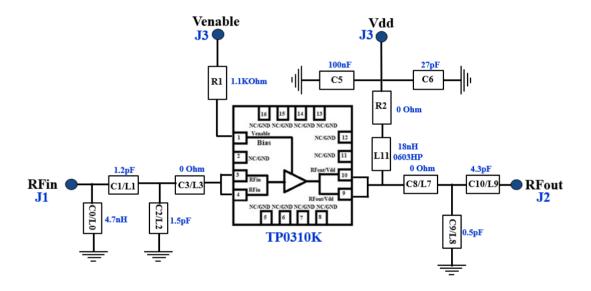
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1. **General Description**

The TP0310K is a power Low Noise Amplifier (LNA) providing high gain and linearity. With a simple input and output match, this LNA can be tuned for different frequency bands targeting low noise, high power, and high linearity over 0.1-3.8GHz frequency band. At 1.85 GHz, the amplifier typically provides 16.5 dB gain, 27.5dBm OP1, +39 dBm OIP3, and a 1.0 dB noise figure, while drawing 140-160 mA current from a +5 V supply.

TP0310K-EVB-A is an evaluation board specially tuned for frequency range of 1700MHz~2000MHz applications. Its application in the areas of Wireless infrastructure, smart cells, cellular repeaters, SDARs Mil/comm radios etc. The TP0310K is packaged in a compact, low-cost Dual Flat No Lead (QFN) 3x3x0.8mm, 16 pin plastic package.

2. TP0310K-EVB-A Board Details



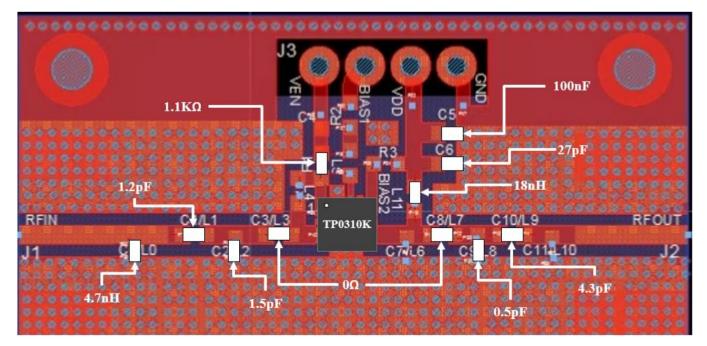


Figure 2.1 TP0310K-EVB-A 1700MHz ~ 2000MHz Schematic and EVB Layout

3. TP0310K-EVB-A Bill of Material

Component ID	Value	Manufacturer Recommended Part Number		
C0/L0	4.7nH	Coil craft 0402HP-4N7XGRW		
C1/L1	1.2pF	Murata GJM1555C1H1R2BB01		
C2/L2	1.5pF	Murata GJM1555C1H1R5BB01		
R1	1.1K	Panasonic ERJ-2RKF1101X		
C9/L8	0.5pF	Murata GJM1555C1HR50BB01		
C10/L9	4.3pF	Murata GJM1555C1H4R3BB0		
C3/L3, C8/L7, R2	0 ohm	Panasonic ERJ-2GE0R00X		
L11	18nH	Coil craft 0402HP-18NXGRW		
C5	100nF	TDK C1005X7R1H104K050BE		
C6	27pF	Murata GJM1555C1H270JB01I		
Q1	GaAs LNA	Tagore Technology TP0310K		
PCB		Rogers RO4350B, 20 mils, 1 oz copper		

Table 3.1 TP0310K-EVB-A BOM

4. TP0310K-EVB-A Biasing Sequence

Turn ON Device	Turn OFF Device		
1. Set Venable to +5V	1. Turn RF power off		
2. Set V _{DD} to +5V	2. Turn off V _{DD}		
3. Device will draw required I _{DQ} current	3. Turn off Venable		
4. Apply RF power			

Table 4.1 TP0310K-EVB-A Bias and Sequencing

5. TP0310K-EVB-A Board Measurement Summary

Frequency (MHz)	EVB Noise figure (dB)	Gain(dB)		OIP3(dBm) 1MHz tone spacing & 8dBm power per tone	S11(dB)	S22(dB)	Mu1
1700	1	17.3	26.8	38.8	-13.3	-13.5	1.1
1850	1	16.8	27.5	39.0	-14.3	-11.4	1.1
2000	1.1	16.1	27.4	39.2	-11.2	-10.4	1.1

Table 5.1 TP0310K-EVB-A Electrical Characteristics Summary



6. TP0310K-EVB-A Test Results

All the tests are carried out at room temperature.

6.1.S parameters

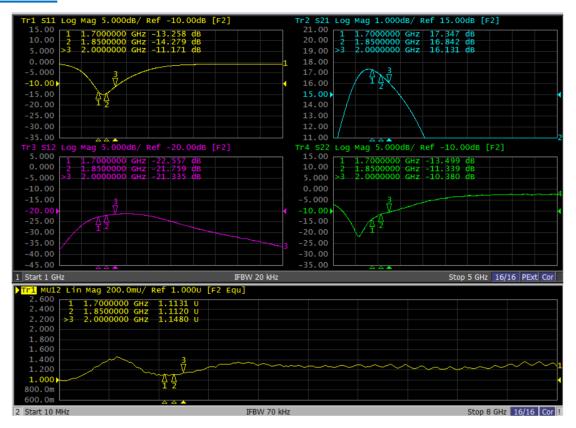


Figure 6.1.1. S parameters of TP0310K-EVB-A

6.2. SMA to SMA Noise Figure

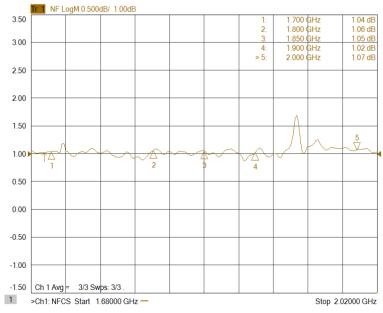


Figure 6.2.1 SMA to SMA NF of TP0310K-EVB-A

6.3. Large Signal Test Results

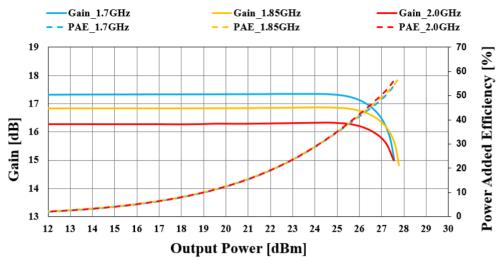


Figure 6.3.1. Gain Vs Pout of TP0310K-EVB-A

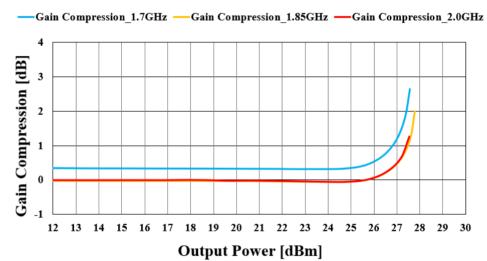


Figure 6.3.2. Gain compression Vs Pout of TP0310K-EVB-A

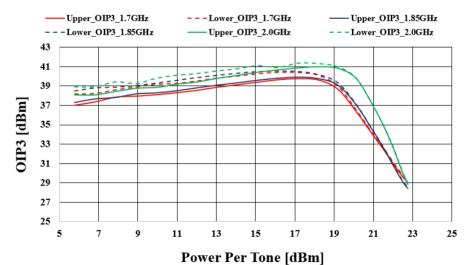


Figure 6.3.3. OIP3 Vs Pout per tone of TP0310K-EVB-A



6.4. ACPR Test Results

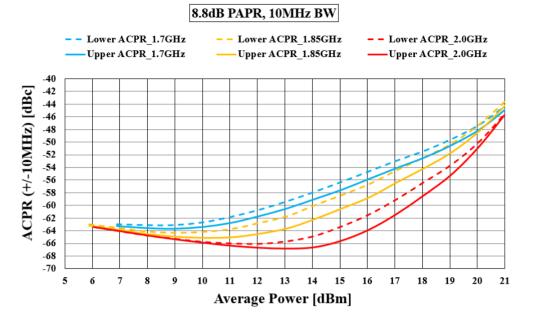


Figure 6.4.1. ACPR vs Average power of TP0310K-EVB-A



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